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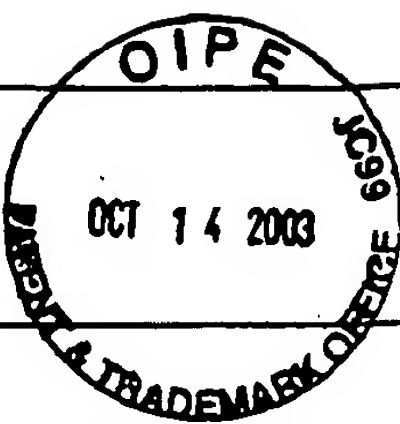
Atty. Docket No.:
H0004337
(1139.1132101)Serial No.:
10/623,351LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION
DISCLOSURE STATEMENT

Applicant: Bernard Q. Li

Filing Date:
July 18, 2003Group Art:
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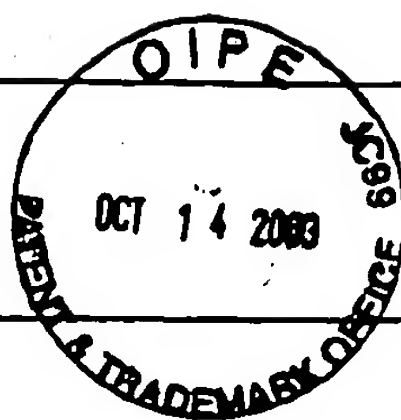
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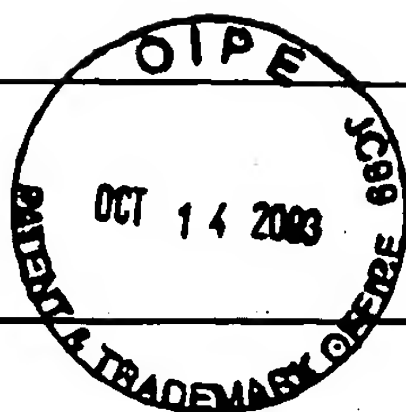
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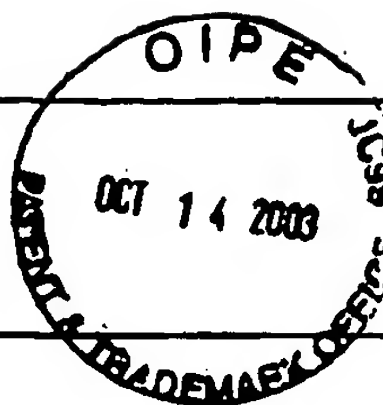
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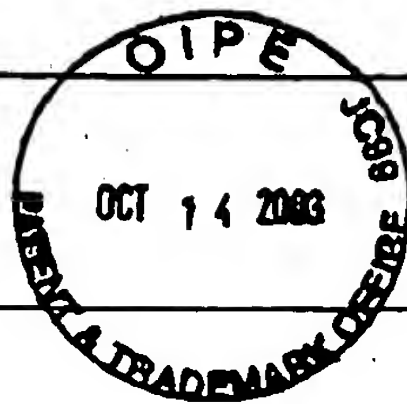
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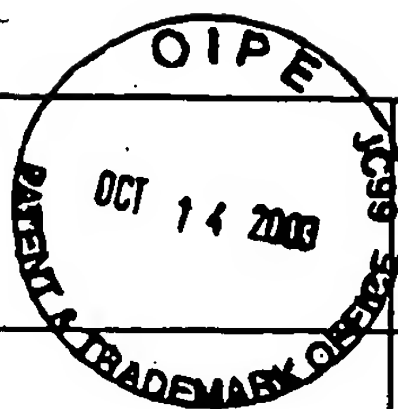
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